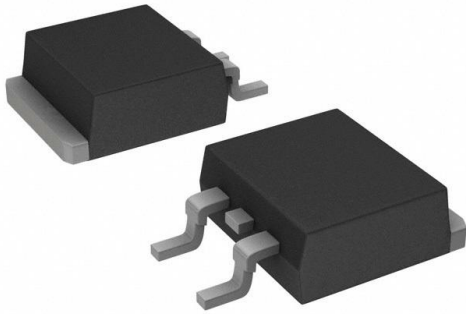


# FDB5800 Datasheet

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DiGi Electronics Part Number	FDB5800-DG
Manufacturer	<a href="#">onsemi</a>
Manufacturer Product Number	FDB5800
Description	MOSFET N-CH 60V 14A/80A D2PAK
Detailed Description	N-Channel 60 V 14A (Ta), 80A (Tc) 242W (Tc) Surface Mount TO-263 (D2PAK)



Tel: +00 852-30501935

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## Purchase and inquiry

Manufacturer Product Number:

FDB5800

Series:

PowerTrench®

FET Type:

N-Channel

Drain to Source Voltage (Vdss):

60 V

Drive Voltage (Max Rds On, Min Rds On):

4.5V, 10V

Vgs(th) (Max) @ Id:

2.5V @ 250µA

Vgs (Max):

±20V

FET Feature:

-

Operating Temperature:

-55°C ~ 175°C (Tj)

Supplier Device Package:

TO-263 (D2PAK)

Base Product Number:

FDB580

Manufacturer:

onsemi

Product Status:

Active

Technology:

MOSFET (Metal Oxide)

Current - Continuous Drain (Id) @ 25°C:

14A (Ta), 80A (Tc)

Rds On (Max) @ Id, Vgs:

6mOhm @ 80A, 10V

Gate Charge (Qg) (Max) @ Vgs:

135 nC @ 10 V

Input Capacitance (Ciss) (Max) @ Vds:

6625 pF @ 15 V

Power Dissipation (Max):

242W (Tc)

Mounting Type:

Surface Mount

Package / Case:

TO-263-3, D2PAK (2 Leads + Tab), TO-263AB

## Environmental & Export classification

RoHS Status:

ROHS3 Compliant

REACH Status:

REACH Unaffected

HTSUS:

8541.29.0095

Moisture Sensitivity Level (MSL):

1 (Unlimited)

ECCN:

EAR99





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November 2013

## FDB5800

### N-Channel Logic Level PowerTrench<sup>®</sup> MOSFET

60 V, 80 A, 6 mΩ

#### Features

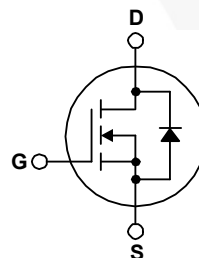
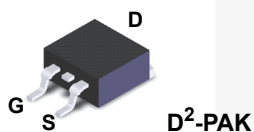
- $R_{DS(on)} = 4.6 \text{ m}\Omega$  (Typ.),  $V_{GS} = 10 \text{ V}$ ,  $I_D = 80 \text{ A}$
- High Performance Trench Technology for Externly Low  $R_{DS(on)}$
- Low Gate Charge
- High Power and Current Handling Capability
- RoHs Compliant

#### Description

This N-Channel MOSFET is produced using Fairchild Semiconductor's advanced PowerTrench<sup>®</sup> process that has been tailored to minimize the on-state resistance while maintaining superior switching performance.

#### Applications

- Power tools
- Motor drives and Uninterruptible Power Supplies



#### Absolute Maximum Ratings $T_C = 25^\circ\text{C}$ unless otherwise noted.

Symbol	Parameter	FDB5800	Unit
$V_{DSS}$	Drain to Source Voltage	60	V
$V_{GS}$	Gate to Source Voltage	$\pm 20$	V
$I_D$	Drain Current		
	- Continuous ( $T_C < 102^\circ\text{C}$ , $V_{GS} = 10 \text{ V}$ )	80	A
	- Continuous ( $T_C < 90^\circ\text{C}$ , $V_{GS} = 5 \text{ V}$ )	80	A
	- Continuous ( $T_{amb} = 25^\circ\text{C}$ , $V_{GS} = 10 \text{ V}$ , with $R_{\theta JA} = 43^\circ\text{C/W}$ )	14	A
	- Pulsed	Figure 4	A
$E_{AS}$	Single Pulse Avalanche Energy (Note 1)	652	mJ
$P_D$	- Power Dissipation	242	W
	- Derate above $25^\circ\text{C}$	1.61	W/ $^\circ\text{C}$
$T_J, T_{STG}$	- Operating and Storage Temperature	-55 to 175	$^\circ\text{C}$

#### Thermal Characteristics

$R_{\theta JC}$	Thermal Resistance Junction to Case TO-263, Max.	0.62	$^\circ\text{C/W}$
$R_{\theta JA}$	Thermal Resistance Junction to Ambient TO-263, Max. (Note 2)	62.5	$^\circ\text{C/W}$
$R_{\theta JA}$	Thermal Resistance Junction to Ambient TO-263, $1\text{in}^2$ copper pad area	43	$^\circ\text{C/W}$

 FDB5800 — N-Channel Logic Level PowerTrench<sup>®</sup> MOSFET

**Package Marking and Ordering Information**

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FDB5800	FDB5800	D <sup>2</sup> -PAK	Tape and Reel	330 mm	24 mm	800 units

**Electrical Characteristics**  $T_C = 25^\circ\text{C}$  unless otherwise noted.

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
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**Off Characteristics**

$B_{VDSS}$	Drain to Source Breakdown Voltage	$I_D = 250 \mu\text{A}, V_{GS} = 0 \text{ V}$	60	-	-	V
$I_{DSS}$	Zero Gate Voltage Drain Current	$V_{DS} = 48 \text{ V}$ $V_{GS} = 0 \text{ V}$	-	-	1	$\mu\text{A}$
		$T_C = 150^\circ\text{C}$	-	-	250	
$I_{GSS}$	Gate to Source Leakage Current	$V_{GS} = \pm 20 \text{ V}$	-	-	$\pm 100$	nA

**On Characteristics**

$V_{GS(TH)}$	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_D = 250 \mu\text{A}$	1.0	-	2.5	V
$r_{DS(ON)}$	Drain to Source On Resistance	$I_D = 80 \text{ A}, V_{GS} = 10 \text{ V}$	-	4.6	6.0	m $\Omega$
		$I_D = 80 \text{ A}, V_{GS} = 4.5 \text{ V}$	-	5.8	7.2	
		$I_D = 80 \text{ A}, V_{GS} = 5 \text{ V}$	-	5.5	7.0	
		$I_D = 80 \text{ A}, V_{GS} = 10 \text{ V},$ $T_J = 175^\circ\text{C}$	-	10	12.6	

**Dynamic Characteristics**

$C_{ISS}$	Input Capacitance	$V_{DS} = 15 \text{ V}, V_{GS} = 0 \text{ V},$ $f = 1 \text{ MHz}$	-	6625	-	pF
$C_{OSS}$	Output Capacitance		-	628	-	pF
$C_{RSS}$	Reverse Transfer Capacitance		-	262	-	pF
$R_G$	Gate Resistance	$V_{GS} = 0.5 \text{ V}, f = 1 \text{ MHz}$	-	1.4	-	$\Omega$
$Q_{g(TOT)}$	Total Gate Charge at 10V	$V_{GS} = 0 \text{ V to } 10 \text{ V}$	-	104	135	nC
$Q_{g(5)}$	Total Gate Charge at 5V	$V_{GS} = 0 \text{ V to } 5 \text{ V}$	-	55	72	nC
$Q_{g(TH)}$	Threshold Gate Charge	$V_{GS} = 0 \text{ V to } 1 \text{ V}$	-	6.0	-	nC
$Q_{gs}$	Gate to Source Gate Charge	$V_{DD} = 30 \text{ V}$ $I_D = 80 \text{ A}$ $I_g = 1.0 \text{ mA}$	-	18.4	-	nC
$Q_{gs2}$	Gate Charge Threshold to Plateau		-	12.5	-	nC
$Q_{gd}$	Gate to Drain "Miller" Charge		-	20.1	-	nC

**Switching Characteristics** ( $V_{GS} = 5\text{V}$ )

$t_{ON}$	Turn-On Time	$V_{DD} = 30 \text{ V}, I_D = 80 \text{ A}$ $V_{GS} = 5 \text{ V}, R_{GS} = 2 \Omega$	-	-	62.1	ns
$t_{d(ON)}$	Turn-On Delay Time		-	20.3	-	ns
$t_r$	Rise Time		-	22.0	-	ns
$t_{d(OFF)}$	Turn-Off Delay Time		-	27.1	-	ns
$t_f$	Fall Time		-	12.1	-	ns
$t_{OFF}$	Turn-Off Time		-	-	59.0	ns

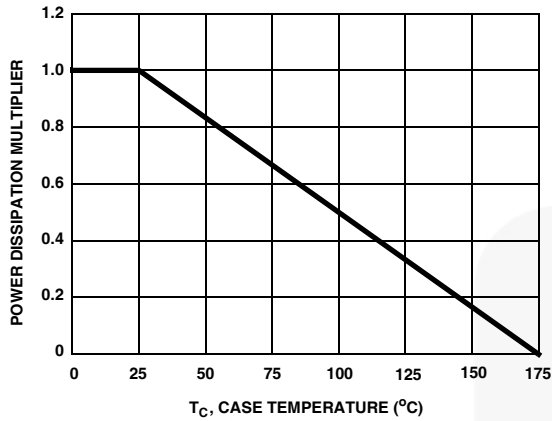
**Drain-Source Diode Characteristics**

$V_{SD}$	Source to Drain Diode Voltage	$I_{SD} = 80 \text{ A}$	-	-	1.25	V
		$I_{SD} = 40 \text{ A}$	-	-	1.0	V
$t_r$	Reverse Recovery Time	$I_{SD} = 60 \text{ A}, dI_{SD}/dt = 100 \text{ A}/\mu\text{s}$	-	-	44	ns
$Q_{SD}$	Reverse Recovered Charge	$I_{SD} = 60 \text{ A}, dI_{SD}/dt = 100 \text{ A}/\mu\text{s}$	-	-	57	nC

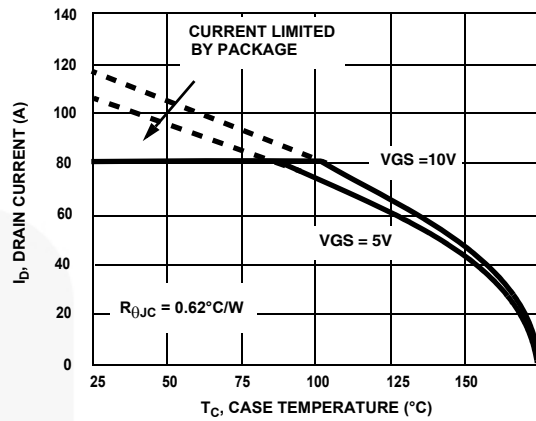
**Notes:**

- Starting  $T_J = 25^\circ\text{C}$ ,  $L = 1\text{mH}$ ,  $I_{AS} = 36\text{A}$ ,  $V_{DD} = 54\text{V}$ ,  $V_{GS} = 10\text{V}$ .
- Pulse width = 100s.

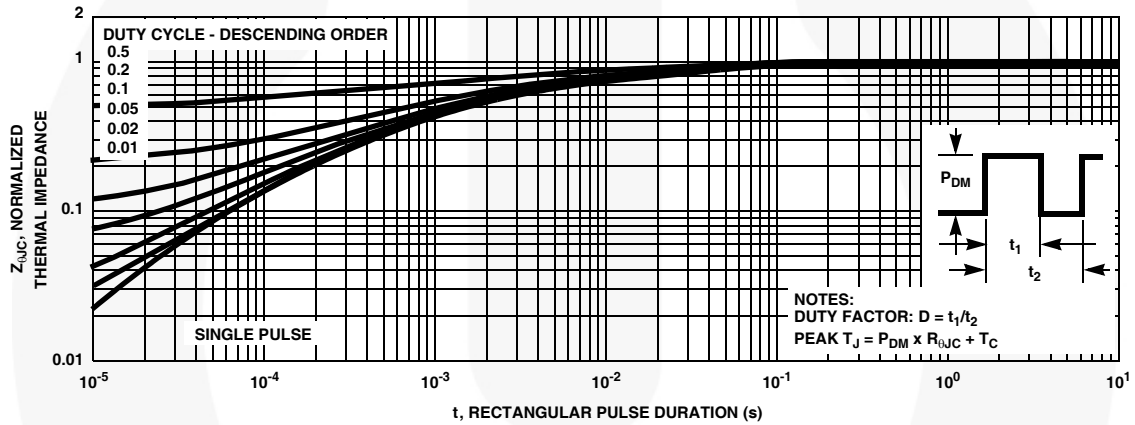
**Typical Characteristics**  $T_C = 25^\circ\text{C}$  unless otherwise noted



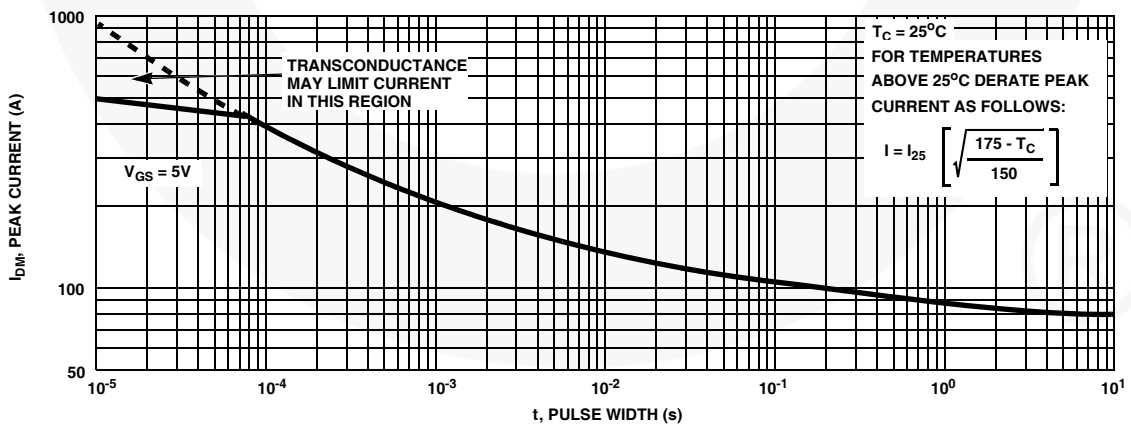
**Figure 1. Normalized Power Dissipation vs Case Temperature**



**Figure 2. Maximum Continuous Drain Current vs Case Temperature**

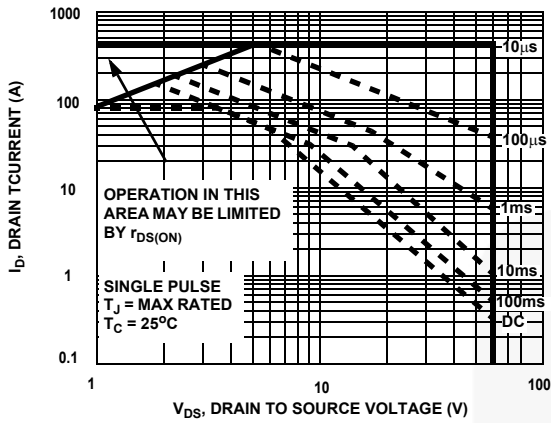


**Figure 3. Normalized Maximum Transient Thermal Impedance**

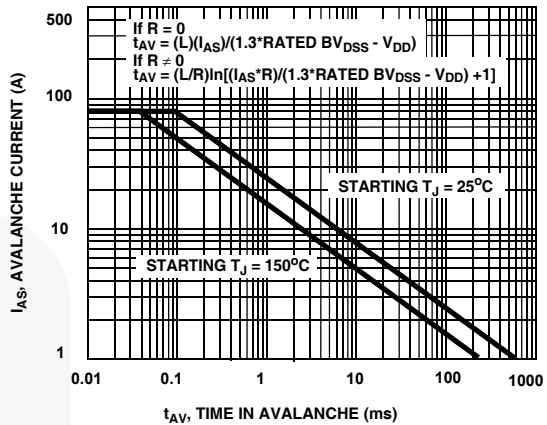


**Figure 4. Peak Current Capability**

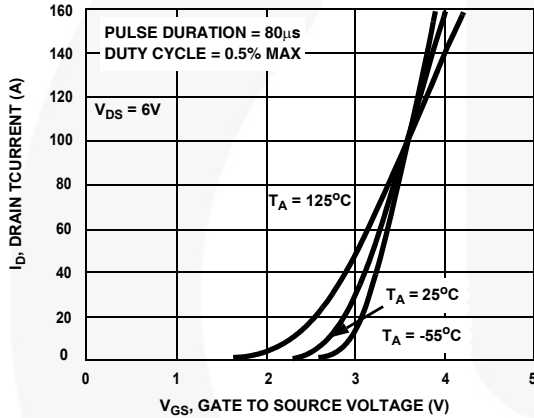
**Typical Characteristics**  $T_C = 25^\circ\text{C}$  unless otherwise noted



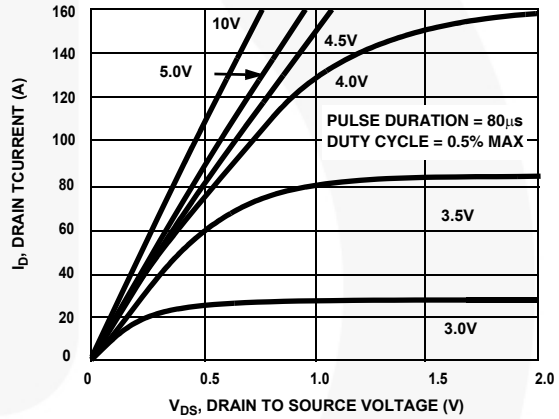
**Figure 5. Forward Bias Safe Operating Area**



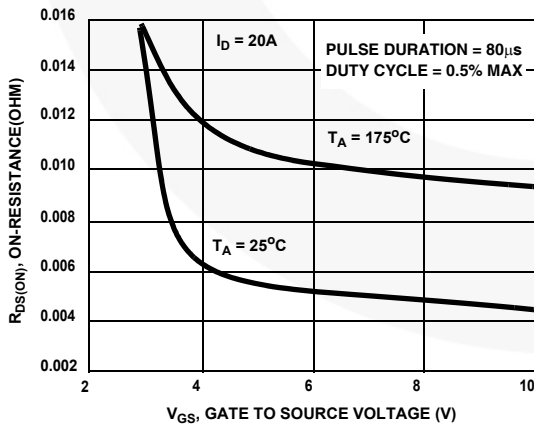
NOTE: Refer to Fairchild Application Notes AN7514 and AN7515  
**Figure 6. Unclamped Inductive Switching Capability**



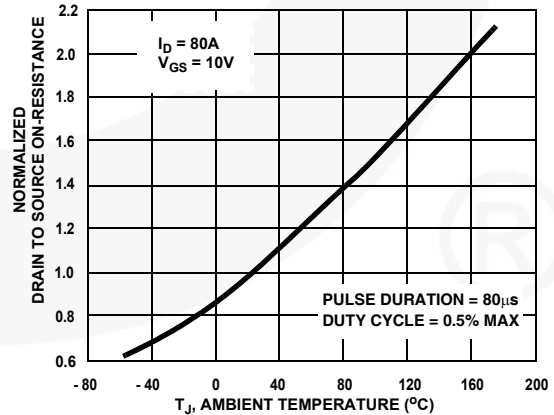
**Figure 7. Transfer Characteristics**



**Figure 8. Saturation Characteristics**

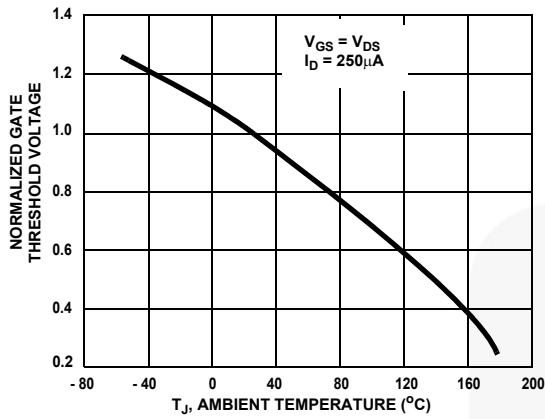


**Figure 9. On-Resistance Variation vs Gate-to-**

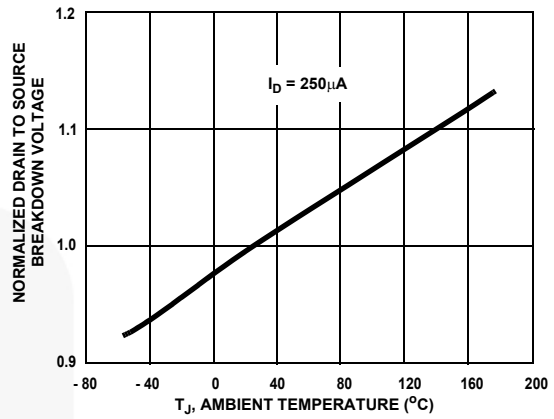


**Figure 10. Normalized Drain to Source On**

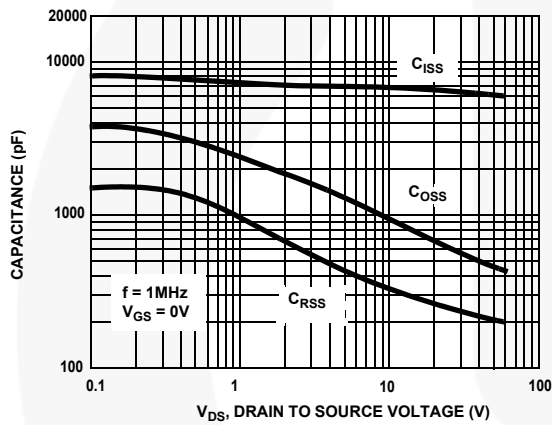
**Typical Characteristics**  $T_C = 25^\circ\text{C}$  unless otherwise noted



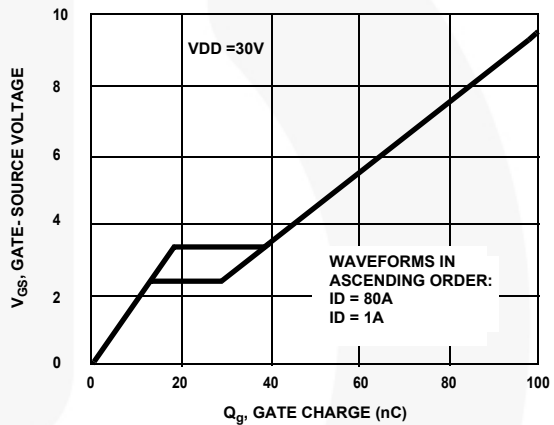
**Figure 11. Normalized Gate Threshold Voltage vs Junction Temperature**



**Figure 12. Normalized Drain to Source Breakdown Voltage vs Junction Temperature**



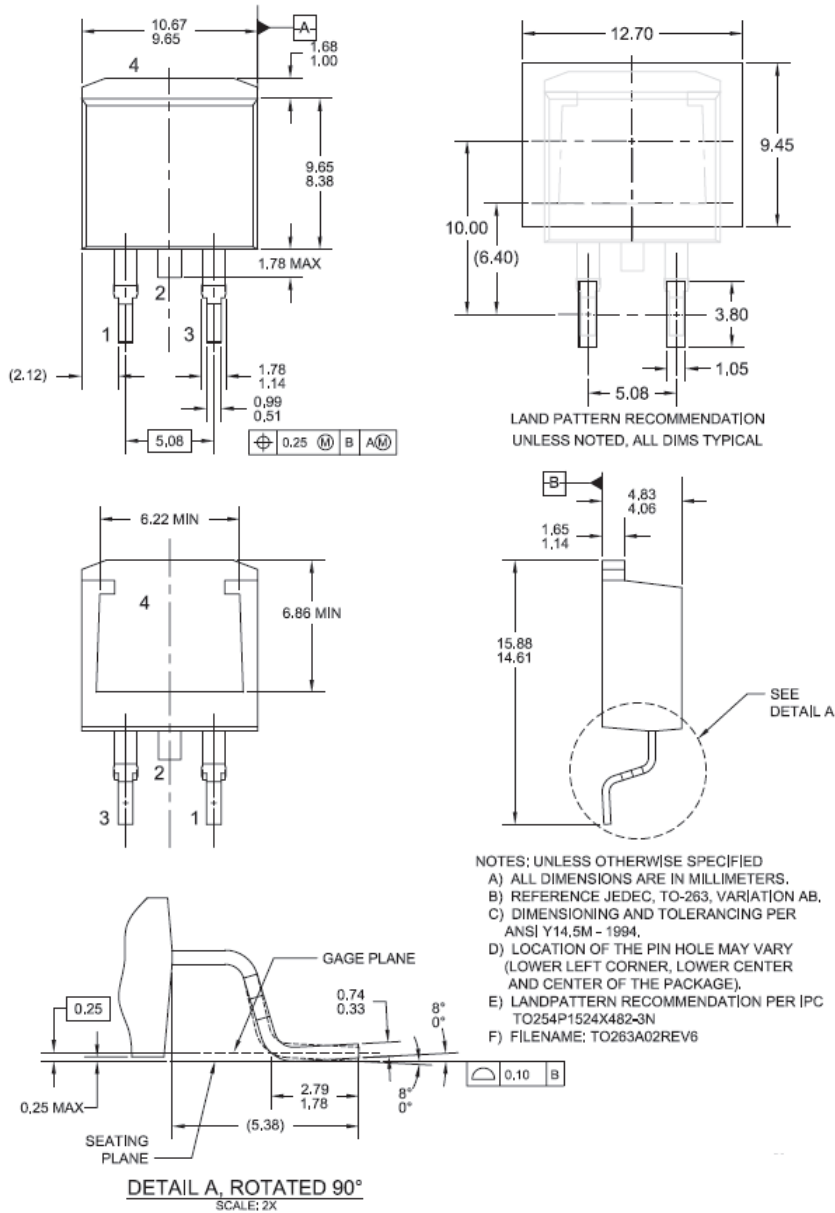
**Figure 13. Capacitance vs Drain to Source Voltage**



**Figure 14. Gate Charge Waveforms for Constant Gate Current**



### Mechanical Dimensions



**Figure 15. TO263 (D<sup>2</sup>PAK), Molded, 2-Lead, Surface Mount**

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